

SEMICONDUCTOR TECHNICAL DATA

KHB9D0N50P1/F1/F2

N CHANNEL MOS FIELD EFFECT TRANSISTOR

General Description

This planar stripe MOSFET has better characteristics, such as fast switching time, low on resistance, low gate charge and excellent avalanche characteristics. It is mainly suitable for electronic ballast and switching mode power supplies.

FEATURES



2007. 5. 10 Revision No : 0